

Electronic Supplementary Material (ESI) for RSC Advances

Tuning the morphology of Co_3O_4 on Ni foam for supercapacitor application

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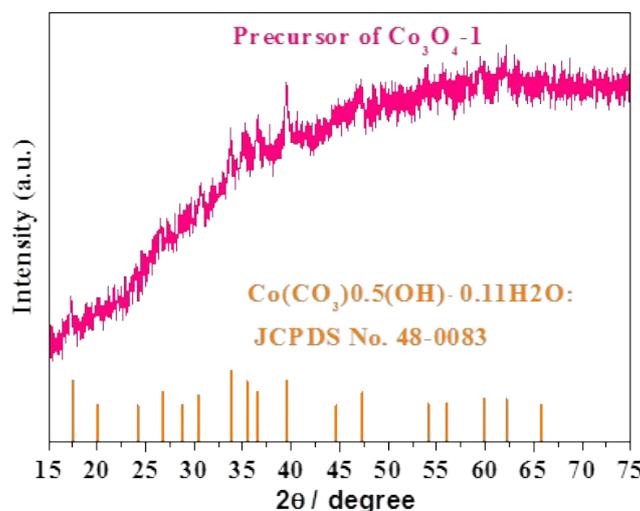


Figure S1 XRD pattern of the Co_3O_4 -1 precursor
(scratched from Ni foam after 6 h hydrothermal reaction).

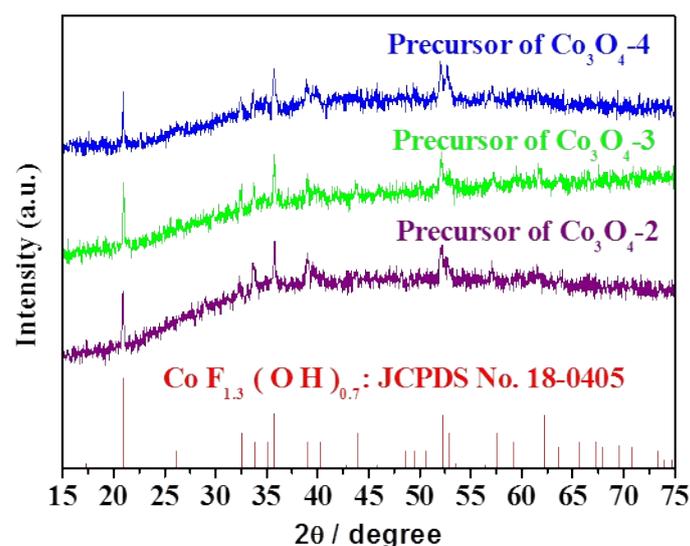


Figure S2 XRD patterns of the Co_3O_4 -2, Co_3O_4 -3, and Co_3O_4 -4 precursors
(scratched from Ni foam after 6 h hydrothermal reaction)

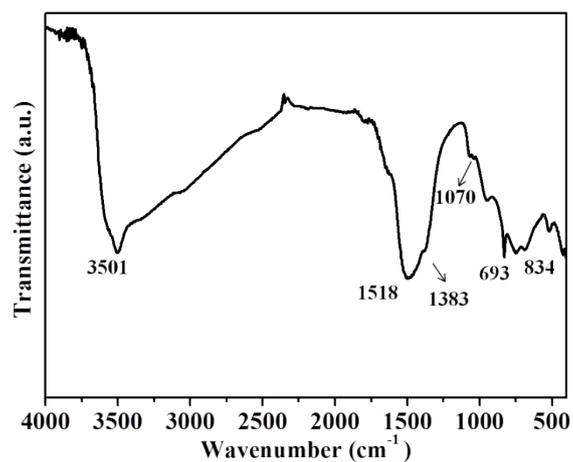


Figure S3 FTIR spectrum of the Co₃O₄-1 precursor (scratched from Ni foam after 6 h hydrothermal reaction).

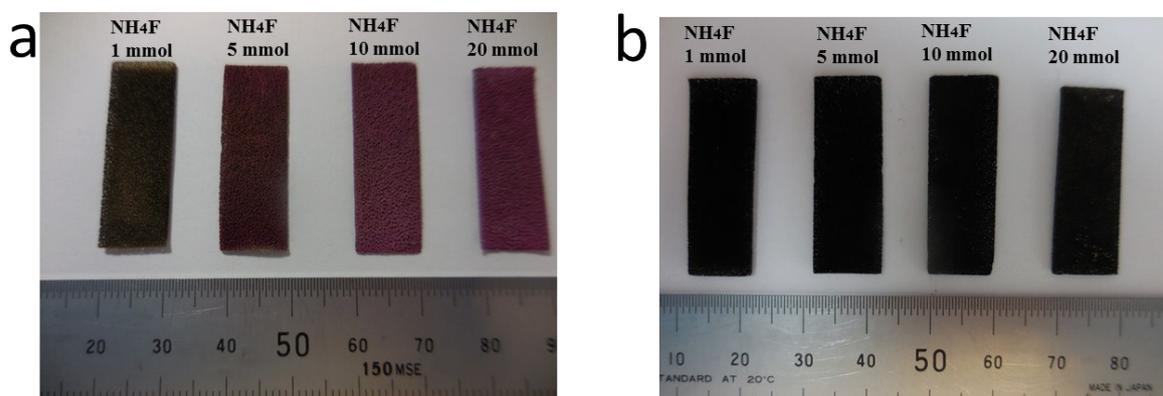


Figure S4 Optical images of precursors of Co₃O₄-1, Co₃O₄-2, Co₃O₄-3, and Co₃O₄-4 (left to right) (a); optical images of Co₃O₄-1, Co₃O₄-2, Co₃O₄-3, and Co₃O₄-4 (left to right) (b).

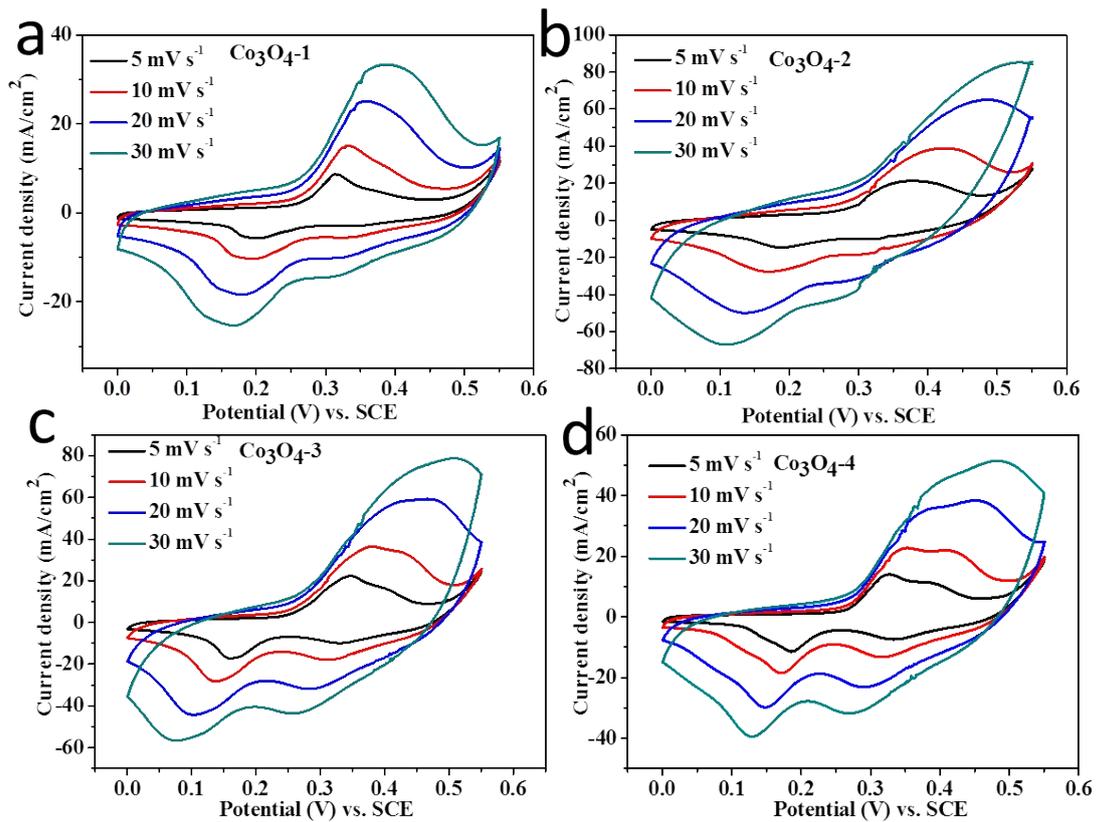


Figure S5 CV curves of Co_3O_4 -1 (a), Co_3O_4 -2 (b), Co_3O_4 -3 (c), and Co_3O_4 -4 (d) at various scan rates.

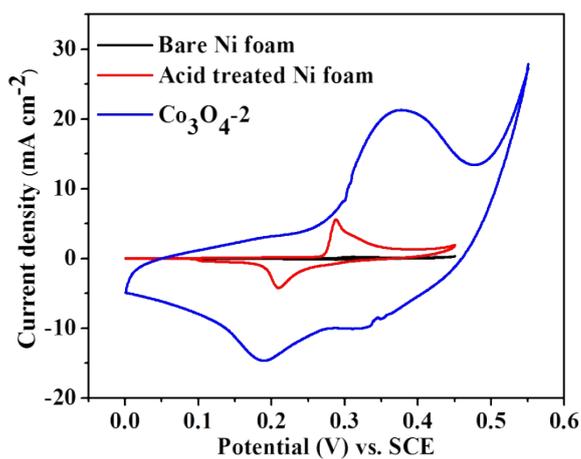


Figure S6 CV curves of bare Ni foam, 6 M hydrochloric acid treated Ni foam and Co_3O_4 -2 at 5 mV s^{-1} scan rate.

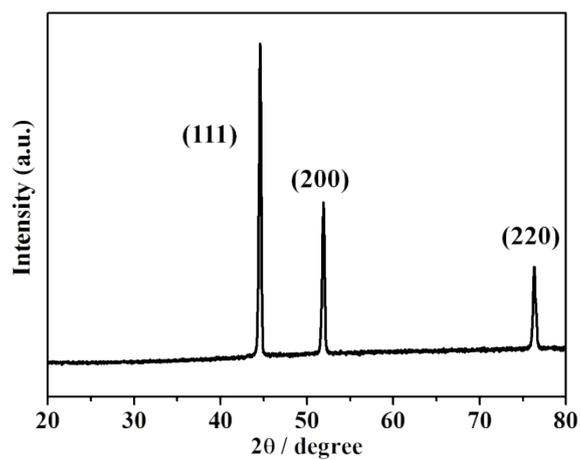


Figure S7 XRD patterns of 6 M hydrochloric acid treated Ni foam

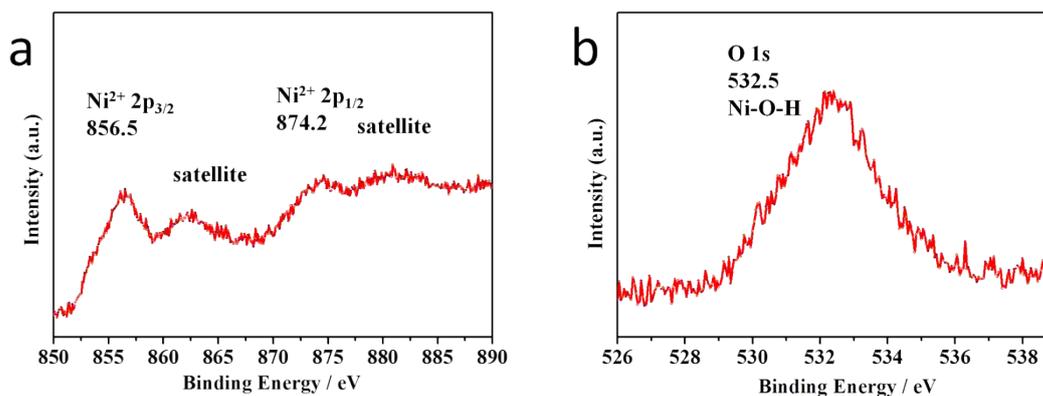


Figure S8 Ni 2p XPS spectra of 6 M hydrochloric acid treated Ni foam (a), O 1s XPS spectra of 6 M hydrochloric acid treated Ni foam (b).

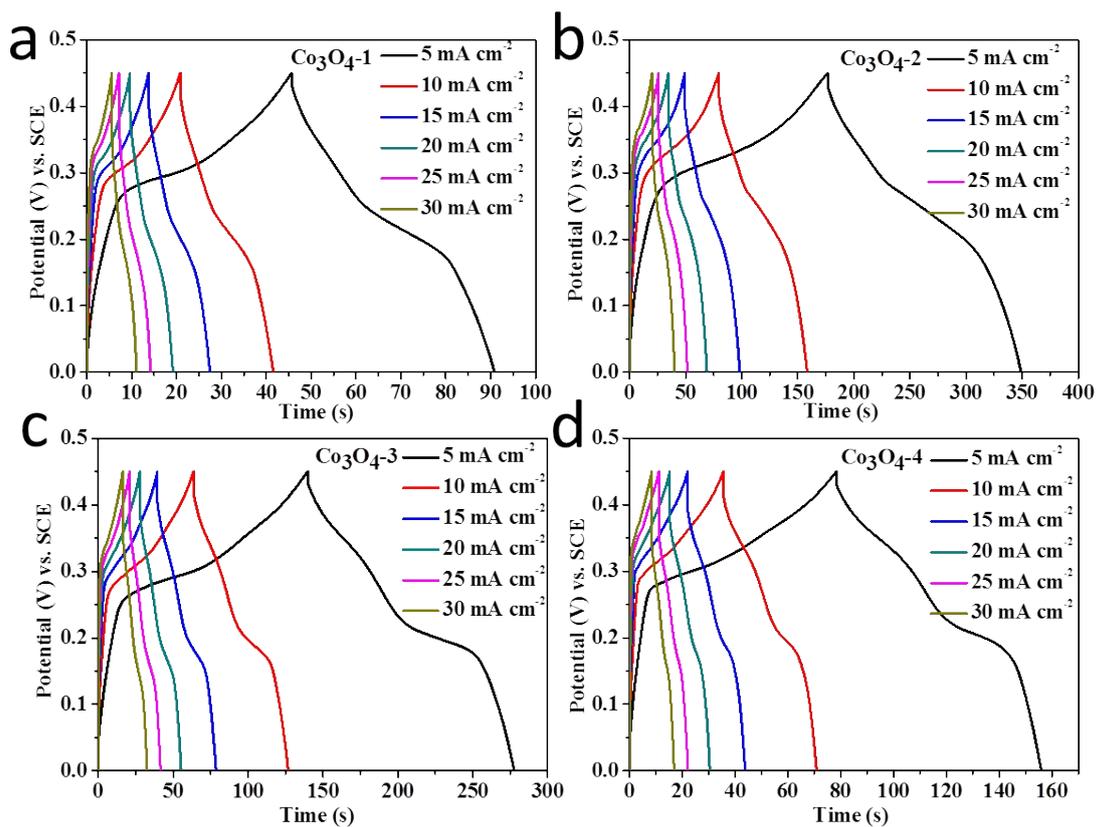


Figure S9 Charge and discharge curves of Co₃O₄-1 (a), Co₃O₄-2 (b), Co₃O₄-3 (c), and Co₃O₄-4 (d) at various current densities.

Table S1 Comparison of values for the specific area capacitance in previously reported works on supercapacitors with values for the four Co₃O₄ materials presented here.

Material	Specific area capacitance (F cm ⁻²)	Reference
Co ₃ O ₄	0.68 (4.2 mA/cm ²)	S1
Co ₃ O ₄ @NiO	1.35 (6 mA/cm ²)	
Co ₃ O ₄	0.135 (11.25 mA/cm ²)	S2
Co ₃ O ₄ @MnO ₂	0.56 (11.25 mA/cm ²)	
CoO	0.285 (5 mA/cm ²)	S3
CoO@PPy	2.51 (5 mA/cm ²)	
Co ₃ O ₄	0.79 (5 mV/s)	S4
Co ₃ O ₄ @NiCo ₂ O ₄	2.04 (5 mV/s)	
NiCo ₂ O ₄	0.84 (2 mA/cm ²)	S5

NiCo ₂ O ₄ @NiCo ₂ O ₄	1.55 (2 mA/cm ²)	
MnO ₂	0.101 (8.5 mA/cm ²)	S6
MnO ₂ @NiO	0.35 (8.5 mA/cm ²)	
NiCo ₂ O ₄	1.5 (8.5 mA/cm ²)	S7
NiCo ₂ O ₄ @MnO ₂	2.54(8.5 mA/cm ²)	
Co ₃ O ₄ -1	0.5 (5 mA/cm ²)	This work
Co ₃ O ₄ -2	1.92 (5 mA/cm ²)	This work
Co ₃ O ₄ -3	1.53 (5 mA/cm ²)	This work
Co ₃ O ₄ -4	0.87 (5 mA/cm ²)	This work

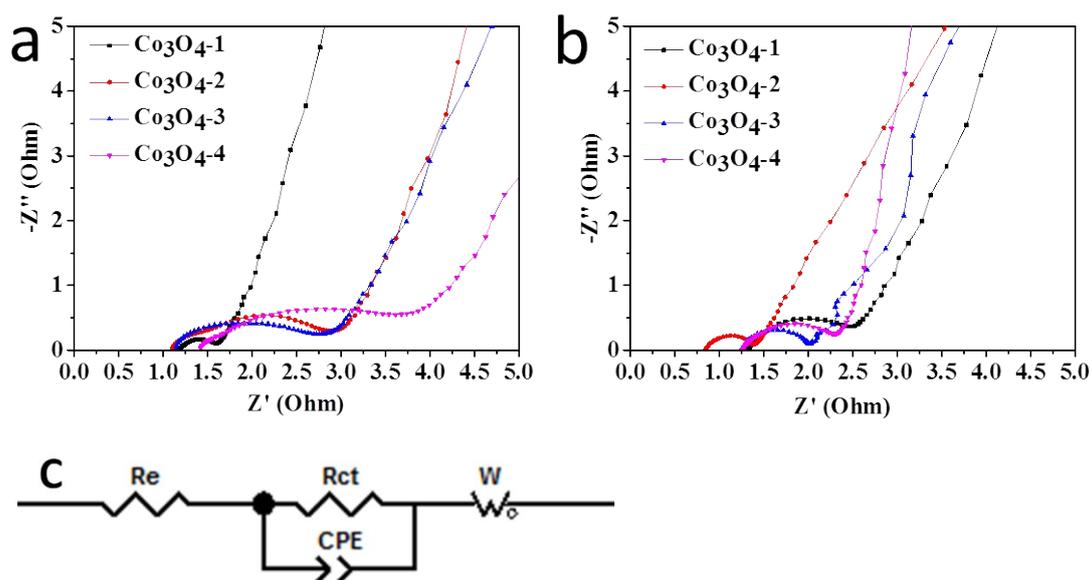


Figure S10 Electrochemical impedance spectroscopy plots of Co₃O₄-1, Co₃O₄-2, Co₃O₄-3, and Co₃O₄-4 before cycling (a), after 3000 cycles (b), and equivalent circuit (c).

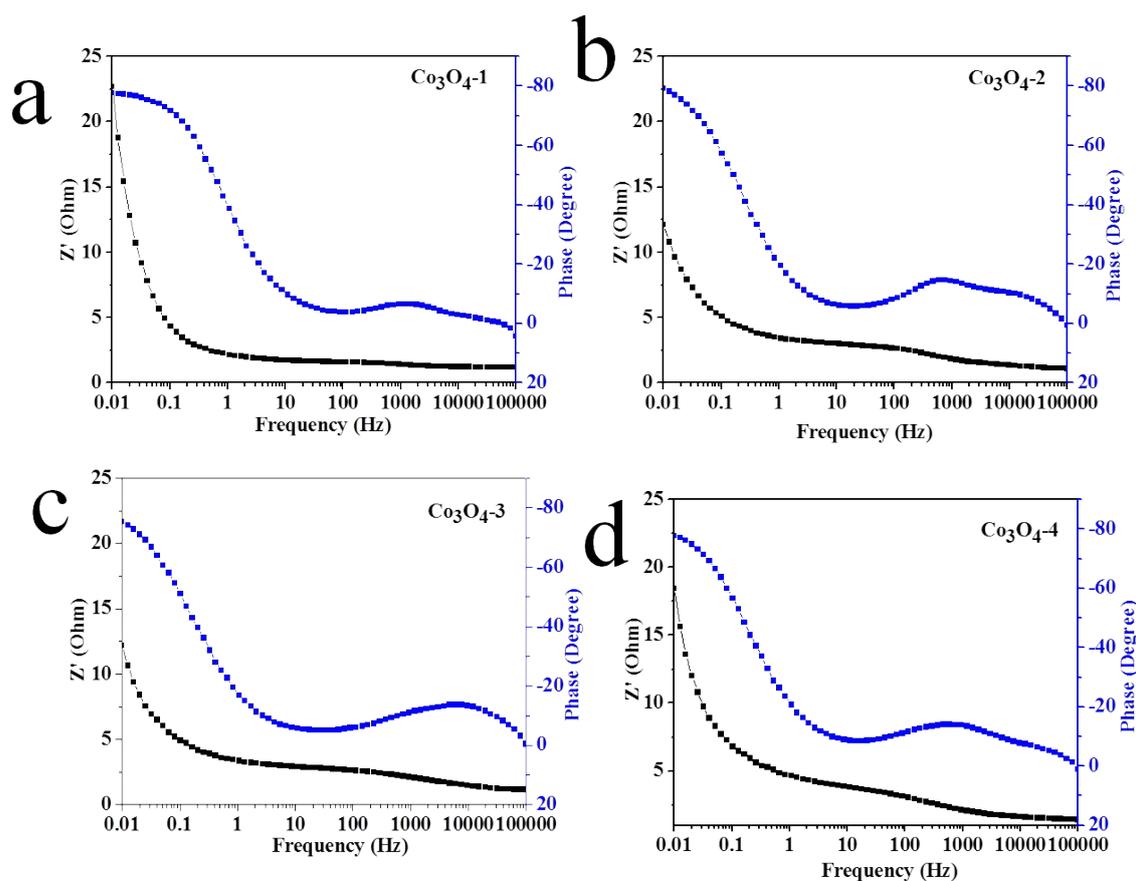


Figure S11 Bode plots of Co_3O_4 -1, Co_3O_4 -2, Co_3O_4 -3, and Co_3O_4 -4.

References:

- S1 X. Xia, J. Tu, Y. Zhang, X. Wang, C. Gu, X. B. Zhao and H. J. Fan, *ACS Nano*, 2012, 6, 5531-5538.
- S2 J. Liu, J. Jiang, C. Cheng, H. Li, J. Zhang, H. Gong and H. J. Fan, *Adv Mater*, 2011, 23, 2076-2081.
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